Precision, Low-Noise Operational Amplifier

General Description

The ET856SXXX series consists of single and dual-channel amplifiers with extremely high precision, featuring ultra-low offset voltage, temperature drift, low input bias current, low noise, and low power consumption. It maintains output stability under capacitive loads of 50pF without external compensation. The amplifier includes a built-in 100Ω series input protection resistor, ensuring no phase inversion even when input signal levels exceed the power supply voltage by several volts.

The ET856SXXX series amplifiers are available in both SOP8 and MSOP8 packages. With a rated operating temperature range of -40°C to +125°C, this product meets the demands of harsh working environments.

The application of this product includes precision diode power measurement, voltage and current level setting, and level detection in optical and wireless transmission systems. Other applications include but are not limited to the following types of circuit power supply and portable instruments and control circuits: thermocouples, resistance temperature detectors, strain bridges, as well as sensor signal conditioning, precision filters, etc.

Features

- Ultra low voltage noise density：4nV/√Hz
- Unit gain bandwidth product：43MHz
- Gain-bandwidth product：80MHz（G=100）
- Dual power supply voltage：±2.25V to ±15V
- Quiescent current：

  ET856S1XX：5.5mA

  ET856S2XX：10mA
- CMRR：＞100dB（Min）
- PSRR：＞100dB（Min）
- Large signal voltage gain：＞120dB（Min）
- Unit gain stability：G≥5
- No inversion
- The internal protection circuit supports input voltage higher than the power supply voltage
- Input offset voltage：

  ET856SXXA：25μV（Max）

  ET856SXXC：150μV（Max）
- Offset Voltage temperature drift：0.3μV/°C
- Bias current：40nA

Applications

- Wireless base station control circuit
- Optical network control circuit
- Thermocouple
- Resistance temperature detector
- Instruments and meters
- Precision filter
- Sensors and control circuits

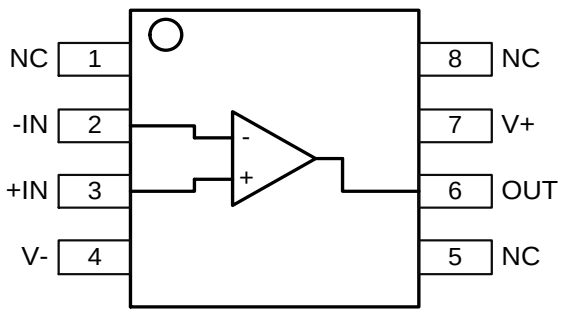
Device information

ET 856S X① X② X③

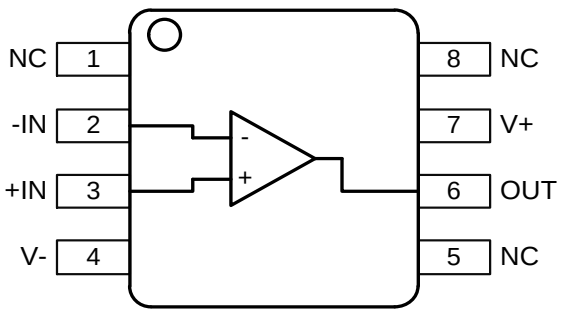
X①Channel number		X②Package		X③Voltage range	
1	Single channel	M	SOP8	A	25μV（Max）
2	Dual channels	U	MSOP8	C	150μV（Max）

Part No.	Package	Packing Option	MSL
ET856S1MA	SOP8	Tape and reel, 3K	3
ET856S1MC	SOP8	Tape and reel, 3K	3
ET856S1UA	MSOP8	Tape and reel, 3K	3
ET856S1UC	MSOP8	Tape and reel, 3K	3
ET856S2MA	SOP8	Tape and reel, 3K	3
ET856S2MC	SOP8	Tape and reel, 3K	3
ET856S2UA	MSOP8	Tape and reel, 3K	3
ET856S2UC	MSOP8	Tape and reel, 3K	3

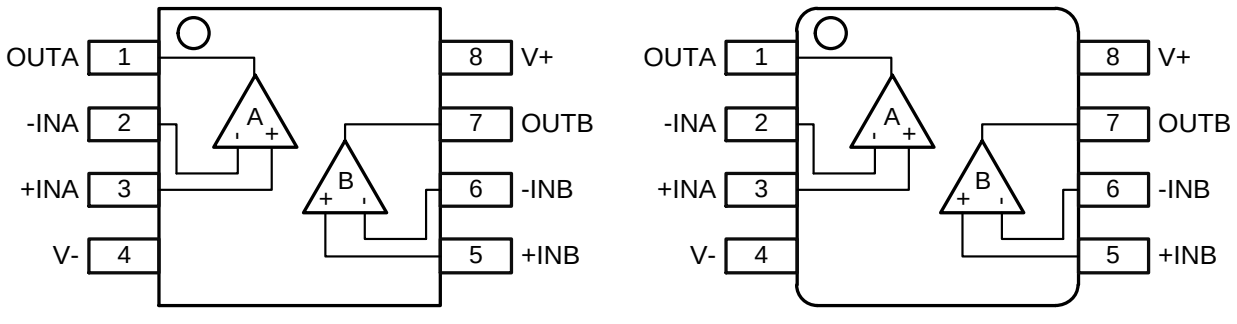
Pin Configuration



ET856S1MA/C-SOP8



ET856S1UA/C-MSOP8



ET856S2MA/C-SOP8 ET856S2UA/C-MSOP8

Top View

Pin Function

Symbol	Descriptions
OUTx	Output
V-	Negative supply
+INx	Non-inverting input
-INx	Inverting input
V+	Positive supply
NC	No conncet

Absolute Maximum Ratings

Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are only stress ratings, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions are not implied. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

Symbol	Parameter	Value	Unit
V_S	Supply Voltage:(V+) - (V-)	±2.25 to ±18	V
V_{IN}	Input Voltage	$(-V_S)$ -0.5 to $(+V_S)$ +0.5	V
T_J	Junction temperature	-65 to +150	°C
T_{STG}	Storage temperature	-65 to +150	°C
V_{ESD}	Human body model (HBM), per ANSI/ESDA/JEDECJS-001(1)	2000	V
	Charged device model (CDM), per JEDEC specification JESD22-C101(2)	1000	V

Note1: JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 500V HBM is possible if necessary precautions are taken.

Note2: JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250V CDM is possible if necessary precautions are taken.

Recommended Operating Conditions

Symbol	Parameter	Value	Unit
V_S	Supply Voltage: (V+) - (V-)	±2.25 to ±15	V
T_A	Operating Temperature Range	-40 to +125	°C

Thermal Characteristics

Symbol	Parameter	Value	Unit
$R_{\theta JA}$	Thermal Characteristics, Thermal Resistance, Junction-to-Air	122.2	°C/W

Electrical Characteristics

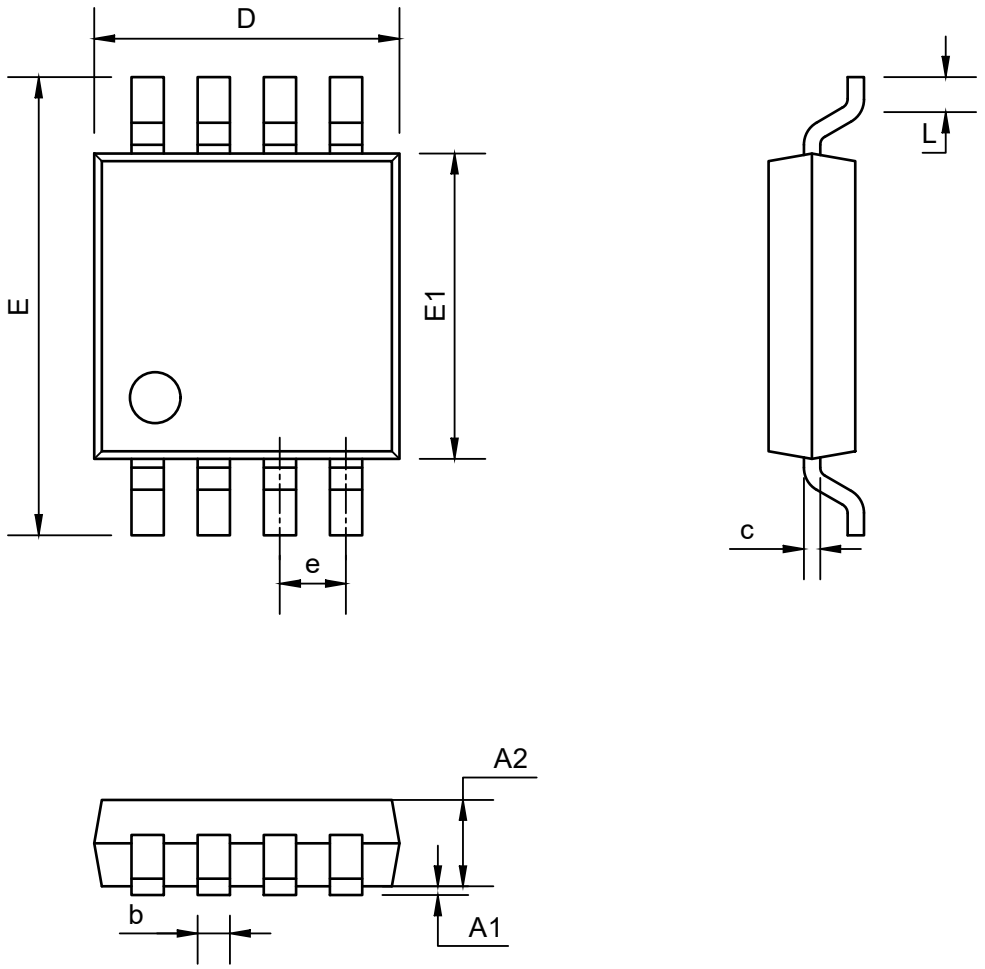
V_S = ±15 V, V_{CM} = 0V, T_A = 25°C(unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
OFFSET VOLTAGE						
V_{OS}	Offset voltage(ET856SXXA)				±25	μV
	Offset voltage(ET856SXXC)				±150	
dV_{OS}/dT	Offset voltage vs temperature	T_A = -40°C to +125°C		0.3		μV/°C
PSRR	Power-supply rejection ratio	V_S = ±2.5 V to ±15 V T_A = -40°C to +125°C	100	120		dB
INPUT BIAS CURRENT						
I_B[(3)]	Input bias current			40		nA
I_{OS}[(3)]	Input offset current			90		nA
NOISE						
e_n	Input voltage noise density	f = 1 kHz		4		nV/√Hz
INPUT VOLTAGE						
V_{CM}	Common-mode voltage range		$-V_S$ +1.5		$+V_S$ - 2	V
CMRR	Common-mode rejection ratio	V_{CM} = -13.5 V to +13 V T_A = -40°C to +125°C	100	120		dB
OPEN-LOOP GAIN						
A_{OL}	Open-loop voltage gain	V_{OUT} = -13.5 V to 13 V, R_L = 2 kΩ	1000	3000		V/mV
FREQUENCY RESPONSE						
GBP	Gain-bandwidth product	R_L = 2 kΩ, G = 1		43		MHz
		R_L = 2 kΩ, G = 100		80		
SR	Slew rate	R_L = 2 kΩ		27		V/μs
THD+N	Total harmonic distortion + noise	V_S = ±12 V, G = 1, V_{OUT} = 2 Vrms, R_L = 600Ω		-80		dB
OUTPUT						
V_{OH}	High output voltage swing	±V_S = ±15V, I_L = 1mA, T_A = −40°C to +125°C	+14	+14.7		V
V_{OL}	Low output voltage swing	±V_S = ±15V, I_L = 1mA, T_A = −40°C to +125°C		-14.7	-14	V
I_{OUT}	Output Current	$V_{DROPOUT}$ < 1.2V		±10		mA
I_{SC}	Short-circuit current		80		180	mA
POWER SUPPLY						
I_Q	ET856S1	Vo=0V		5.5		mA
	ET856S2			10		

Note3: Guaranteed by design.

Package Dimension

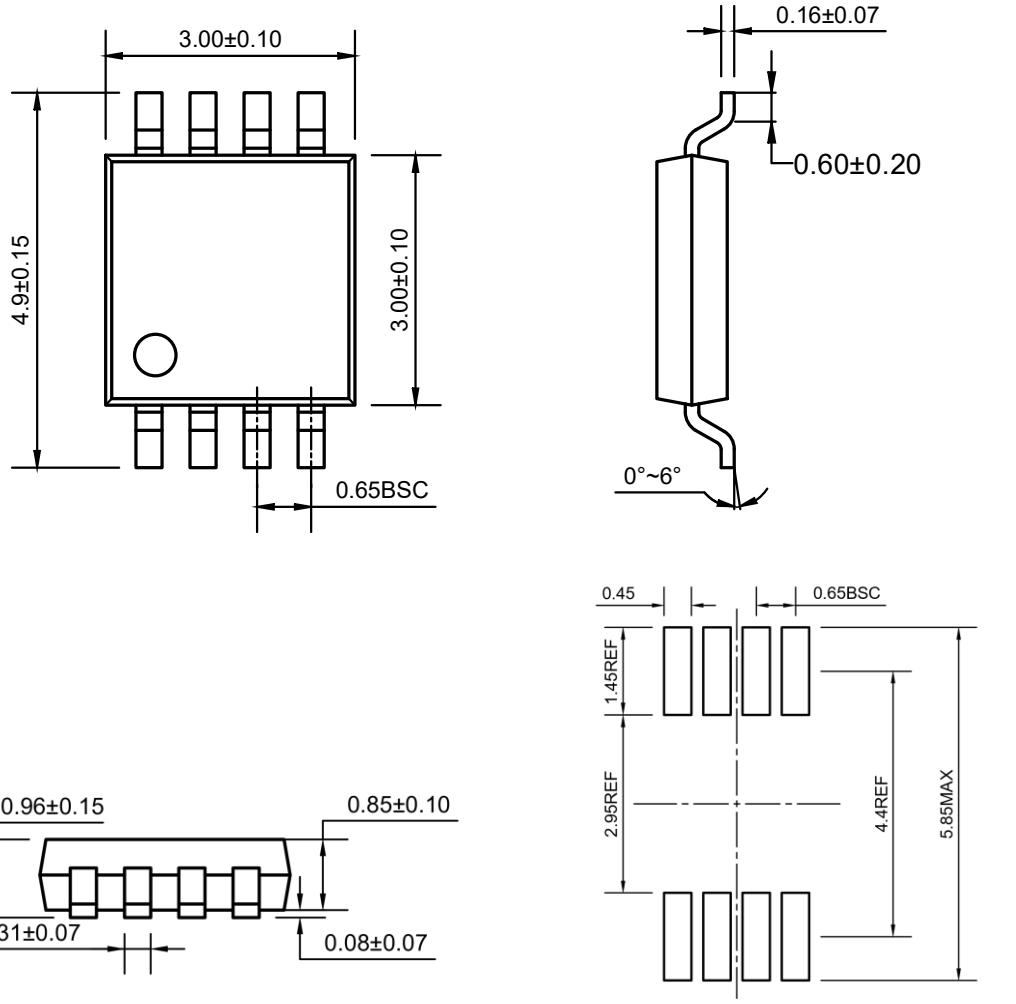
SOP8



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
A1	0.10	—	0.225
A2	1.30	1.40	1.50
b	0.39	—	0.47
c	0.20	—	0.24
D	4.80	4.90	5.00
E	5.80	6.00	6.20
E1	3.80	3.90	4.00
e	1.27 BSC		
L	0.50	—	0.80

MSOP8



Recommended Land Pattern

Unit: mm

Revision History and Checking Table

Version	Date	Revision Item	Modifier	Function & Spec Checking	Package & Tape Checking
1.0	2024-07-23	Preliminary Version	Jiangqp,Huyt	Shibo	Liujy
1.1	2024-08-06	Update Electrical Characteristics	Huyt	Shibo	Liujy
1.2	2026-01-23	Update Note	Huyt	Shibo	Liujy